

Product Summary

BV _{bss}	R _{DS(ON)} Max	I _D T _A = +25°C
30V	60mΩ @ V _{GS} = 8V	3.9A
	72mΩ @ V _{GS} = 4.5V	3.5A

Description

This new generation MOSFET is designed to minimize the footprint in handheld and mobile application. The device can be used to replace many small signal MOSFETs with minimal footprint.

Applications

- Battery managements
- Load switches
- Battery protections
- Handheld and mobile applications

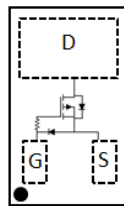
Features and Benefits

- Low Q_g & Q_{gd}
- Small Footprint
- Low Profile 0.20mm Height
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:contact@diodes.com) or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>

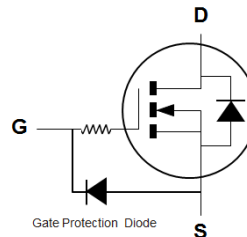
Mechanical Data

- Package: X4-DSN1006-3
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – NiPdAu or NiAu. Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.00029 grams (Approximate)

X4-DSN1006-3



Top View



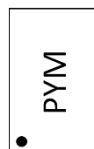
Equivalent Circuit

Ordering Information (Note 4)

Part Number	Package	Packing	
		Qty.	Carrier
DMN3060LCA3-7	X4-DSN1006-3	10000	Tape & Reel
DMN3060LCA3-7A	X4-DSN1006-3	10000	Tape & Reel

- Notes:
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



P = Product Type Marking Code
 YM = Date Code Marking
 Y or \bar{Y} = Year (ex: J = 2022)
 M or \bar{M} = Month (ex: 9 = September)

Date Code Key

Year	2017	...	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	E	...	J	K	L	M	N	O	P	R	S	T

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GS}	12	V
Continuous Drain Current (Note 5) V _{GS} = 8V	Steady State	T _A = +25°C	I _D	3.9	A
		T _A = +70°C		3.1	
Continuous Drain Current (Note 5) V _{GS} = 4.5V	Steady State	T _A = +25°C	I _D	3.5	A
		T _A = +70°C		2.8	
Pulsed Drain Current (Note 6)			I _{DM}	20	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	P _D	0.79	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 7)	R _{θJA}	160	°C/W
Power Dissipation (Note 5)	P _D	1.35	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	R _{θJA}	93	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	30	—	—	V	V _{GS} = 0V, I _D = 250μA
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	—	—	100	nA	V _{DS} = 24V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	50	nA	V _{GS} = 10V, V _{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	0.65	0.83	1.10	V	V _{DS} = V _{GS} , I _D = 250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	46	60	mΩ	V _{GS} = 8V, I _D = 0.5A
		—	52	72		V _{GS} = 4.5V, I _D = 0.5A
		—	69	110		V _{GS} = 2.5V, I _D = 0.5A
		—	101	160		V _{GS} = 1.8V, I _D = 0.5A
Diode Forward Voltage	V _{SD}	—	0.7	0.9	V	V _{GS} = 0V, I _S = 0.5A
Reverse Recovery Charge	Q _{RR}	—	2.4	—	nC	V _{DD} = 15V, I _F = 0.5A,
Reverse Recovery Time	t _{RR}	—	7.1	—	ns	di/dt = 300A/μs
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	—	128	—	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	—	81	—		
Reverse Transfer Capacitance	C _{rss}	—	6.3	—		
Series Gate Resistance	R _g	—	20.9	—	Ω	f = 1MHz, V _{GS} = 0V, V _{DS} = 0V
Total Gate Charge	Q _g	—	1118	—	pC	V _{GS} = 4.5V, V _{DS} = 15V, I _D = 0.5A
Gate-Source Charge	Q _{gs}	—	163	—		
Gate-Drain Charge	Q _{gd}	—	241	—		
Gate Charge at V _{TH}	Q _{g(TH)}	—	130	—		
Turn-On Delay Time	t _{D(ON)}	—	5.3	—	ns	V _{DS} = 15V, V _{GS} = 4.5V, R _g = 2Ω, I _D = 0.5A
Turn-On Rise Time	t _r	—	2.1	—		
Turn-Off Delay Time	t _{D(OFF)}	—	12.9	—		
Turn-Off Fall Time	t _f	—	5.4	—		

- Notes:
- Device mounted on FR-4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.
 - Repetitive rating, pulse width limited by junction temperature.
 - Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to production testing.

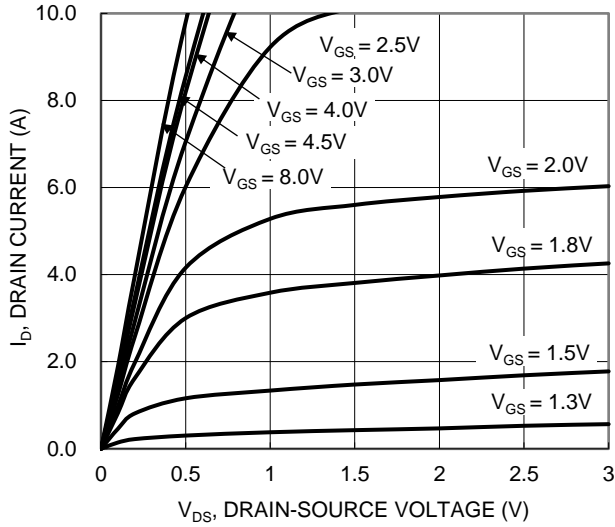


Figure 1. Typical Output Characteristic

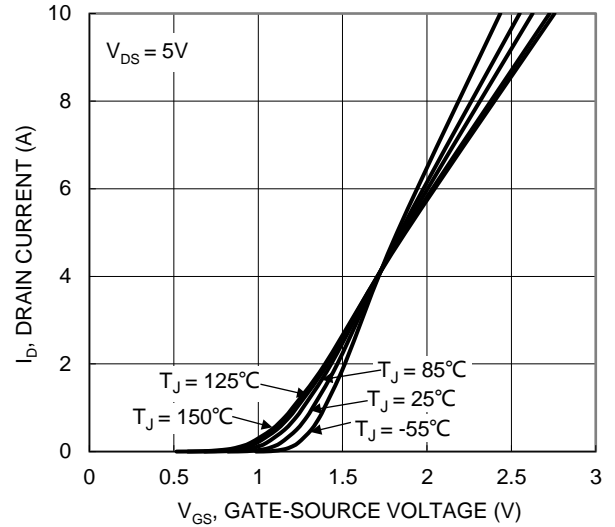


Figure 2. Typical Transfer Characteristic

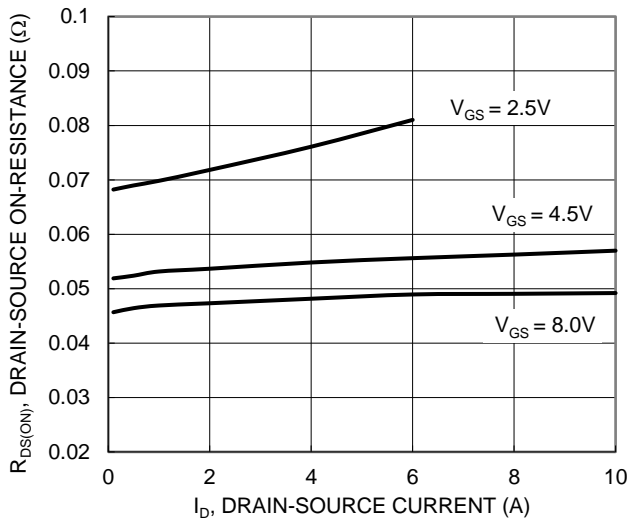


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

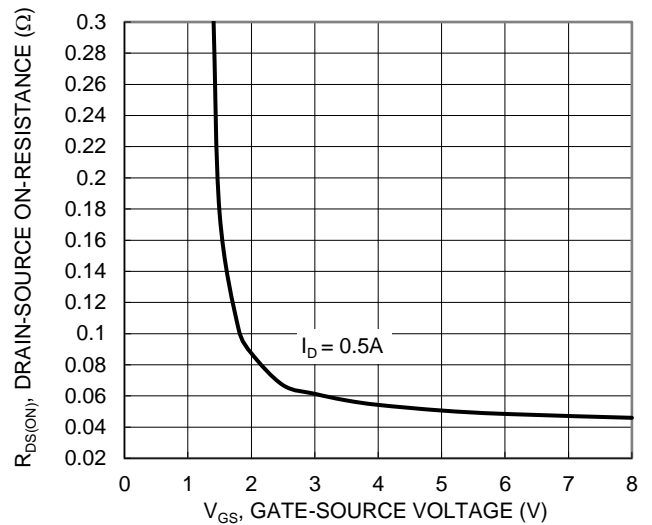


Figure 4. Typical Transfer Characteristic

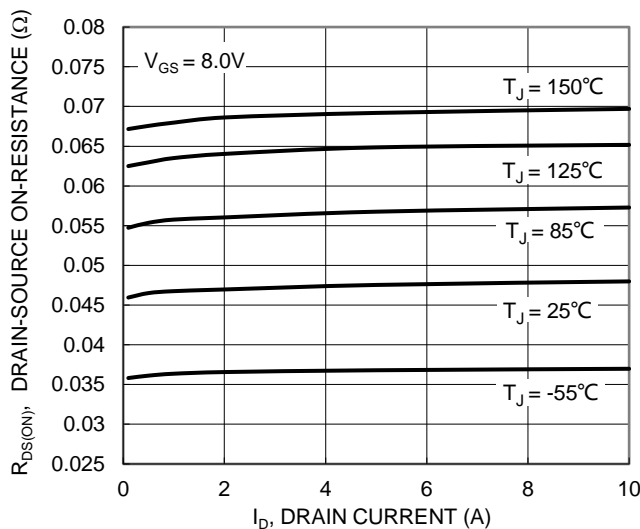


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

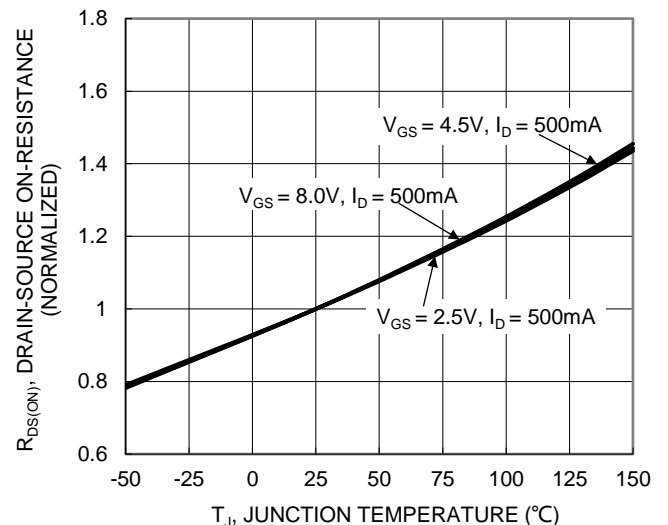


Figure 6. On-Resistance Variation with Junction Temperature

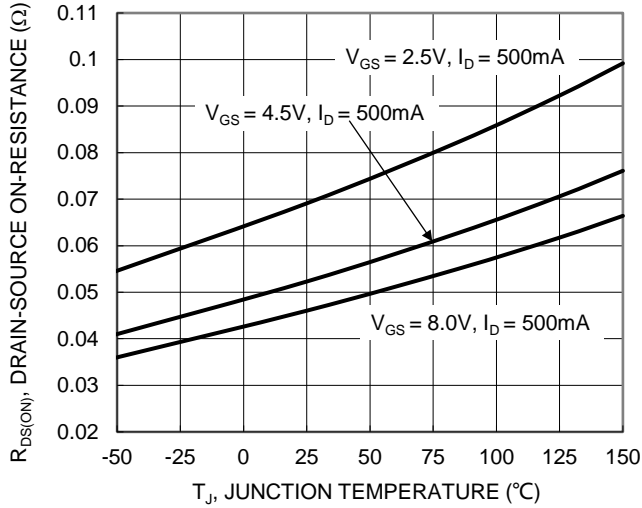


Figure 7. On-Resistance Variation with Junction Temperature

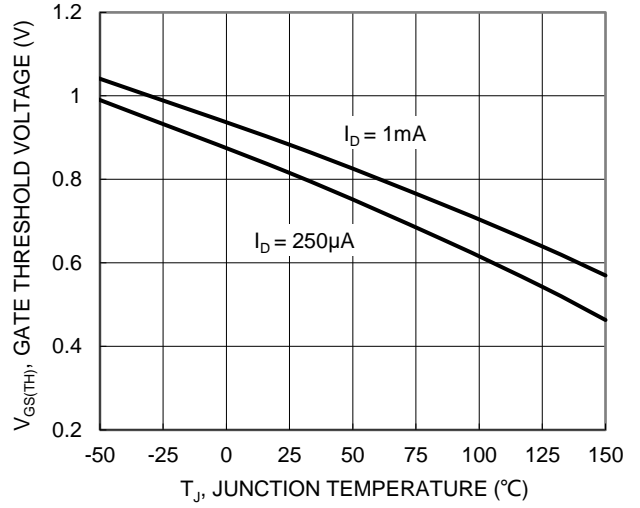


Figure 8. Gate Threshold Variation vs. Junction Temperature

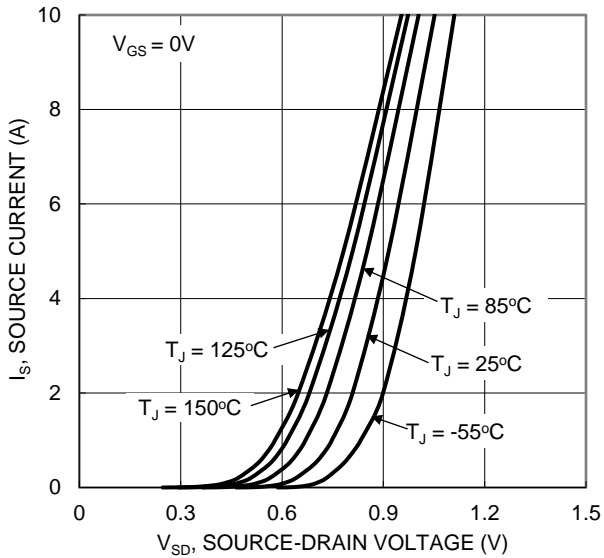


Figure 9. Diode Forward Voltage vs. Current

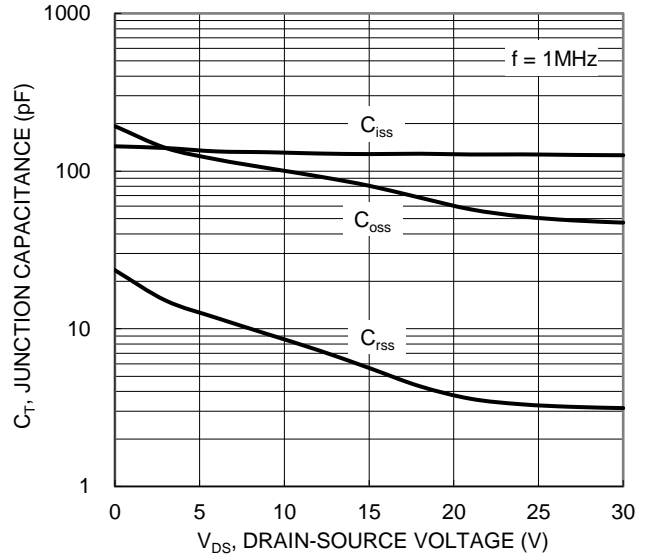


Figure 10. Typical Junction Capacitance

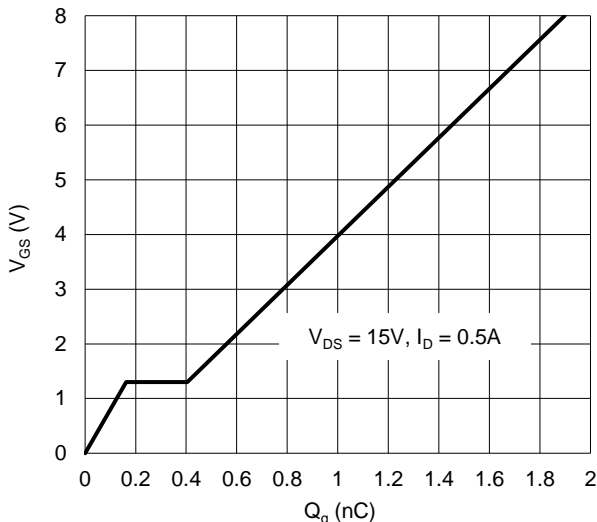


Figure 11. Gate Charge

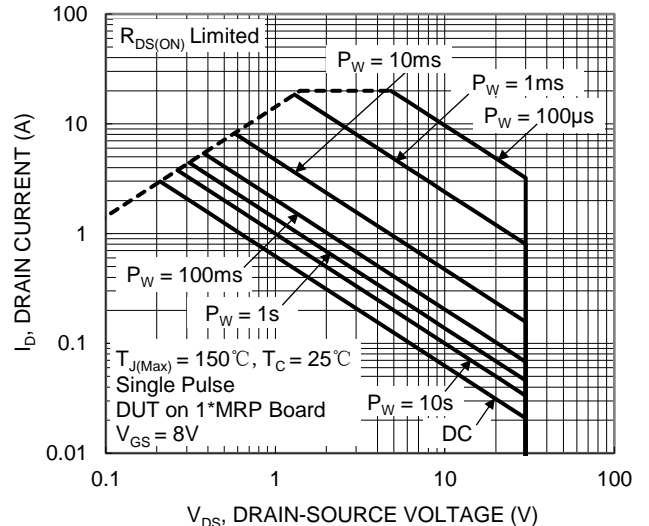


Figure 12. SOA, Safe Operation Area

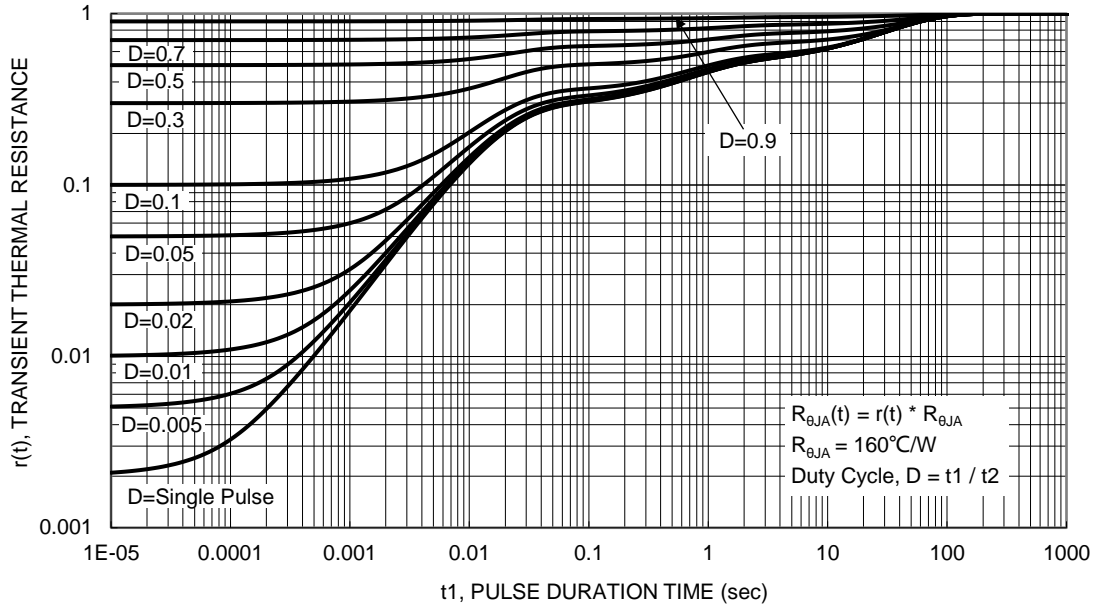
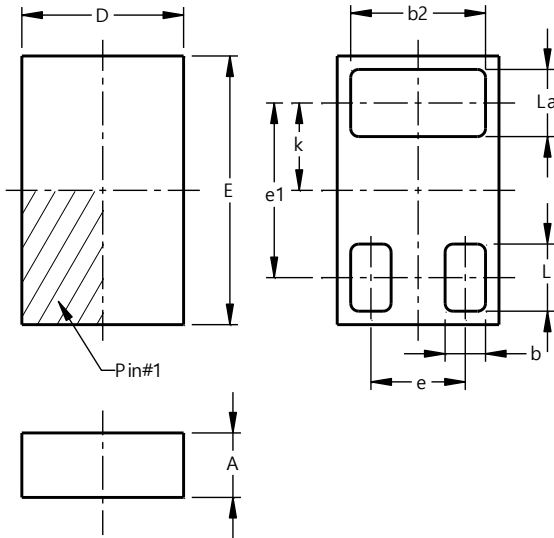


Figure 13. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X4-DSN1006-3

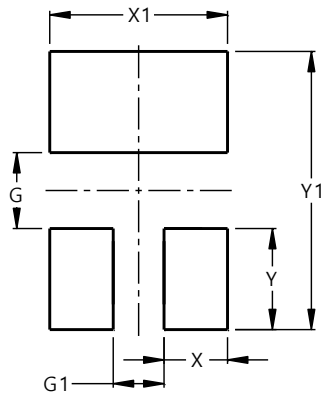


X4-DSN1006-3			
Dim	Min	Max	Typ
A	0.18	0.22	0.20
b	0.14	0.16	0.15
b2	0.49	0.51	0.50
D	0.56	0.64	0.60
E	0.96	1.04	1.00
e	—	—	0.35
e1	—	—	0.65
k	—	—	0.325
L	0.24	0.26	0.25
La	0.24	0.26	0.25
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X4-DSN1006-3

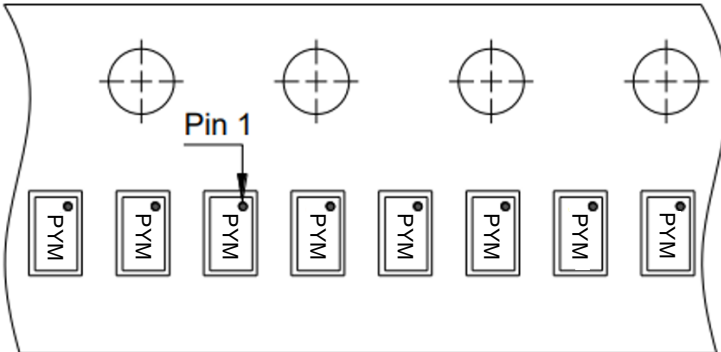


Dimensions	Value (in mm)
G	0.40
G1	0.20
X	0.15
X1	0.50
Y	0.25
Y1	0.90

Tape and Reel Information

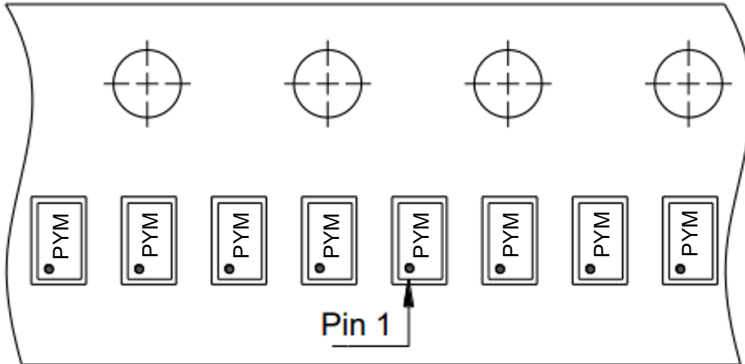
Please see <https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf> for the latest version.

DMN3060LCA3-7



DMN3060LCA3-7A

Change the PIN1 orientation in the carrier tape, rotate 180 degree to meet customer demand (Top side).



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